The RF Line NPN Silicon RF Power Transistor

... designed for power amplifier applications in industrial, commercial and amateur radio equipment to 30 MHz.

 Specified 12.5 Volt, 30 MHz Characteristics — Output Power = 60 Watts Minimum Gain = 13 dB Efficiency = 55%

MATCHING PROCEDURE

In the push–pull circuit configuration it is preferred that the transistors are used as matched pairs to obtain optimum performance.

The matching procedure used by Motorola consists of measuring hFE at the data sheet conditions and color coding the device to predetermined hFE ranges within the normal hFE limits. A color dot is added to the marking on top of the cap. Any two devices with the same color dot can be paired together to form a matched set of units.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	VCEO	18	Vdc
Collector–Emitter Voltage	VCES	36	Vdc
Emitter-Base Voltage	VEBO	4.0	Vdc
Collector Current — Continuous	ΙC	15	Adc
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	175 1.0	Watts W/°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

MRF455

60 W, 30 MHz

RF POWER

TRANSISTOR NPN SILICON

CASE 211-07, STYLE 1

THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Thermal Resistance, Junction to Case	R _{θJC}	1.0	°C/W

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage (I _C = 100 mAdc, I _B = 0)	V(BR)CEO	18	-	—	Vdc
Collector–Emitter Breakdown Voltage $(I_{C} = 50 \text{ mAdc}, V_{BE} = 0)$	V(BR)CES	36	-	—	Vdc
Emitter–Base Breakdown Voltage (I _E = 10 mAdc, I _C = 0)	V(BR)EBO	4.0	-	—	Vdc
ON CHARACTERISTICS			-		
DC Current Gain (I _C = 5.0 Adc, V _{CE} = 5.0 Vdc)	hFE	10	-	150	_
DYNAMIC CHARACTERISTICS					
Output Capacitance (V _{CB} = 12.5 Vdc, I _E = 0, f = 1.0 MHz)	C _{ob}	—	-	250	pF
	•	•		•	(agenting and)

(continued)



ELECTRICAL CHARACTERISTICS — continued ($T_C = 25^{\circ}C$ unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
FUNCTIONAL TESTS (Figure 1)	•		•		
Common–Emitter Amplifier Power Gain (V _{CC} = 12.5 Vdc, P _{out} = 60 W, f = 30 MHz)	G _{pe}	13	-	—	dB
Collector Efficiency (V _{CC} = 12.5 Vdc, P _{out} = 60 W, f = 30 MHz)	η	55	-	_	%
Series Equivalent Input Impedance (V _{CC} = 12.5 Vdc, P _{out} = 60 W, f = 30 MHz)	Z _{in}	-	1.66–j.844	_	Ohms
Series Equivalent Output Impedance (V _{CC} = 12.5 Vdc, P _{Out} = 60 W, f = 30 MHz)	Z _{out}	-	1.73–j.188	_	Ohms
Parallel Equivalent Input Impedance (V _{CC} = 12.5 Vdc, P _{out} = 60 W, f = 30 MHz)	Z _{in}	-	2.09/1030	—	Ω/pF
Parallel Equivalent Output Impedance (V _{CC} = 12.5 Vdc, P _{OUt} = 60 W, f = 30 MHz)	Z _{out}	-	1.75/330	—	Ω/pF







PACKAGE DIMENSIONS



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